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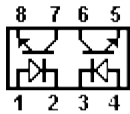
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## ISD202: OPTICALLY COUPLED ISOLATORS

### Circuit



### Features

- 5000 V Isolation.
- High Current Transfer Ratio (125% to 250%).
- Low Cost Dual-In-Line Package.
- Dual Configuration.

### Description

The ISD202 is an optically coupled isolator. Each channel consists of a Gallium Arsenide infrared emitting diode and an NPN silicon phototransistor mounted in a standard 6-pin dual-in-line package. Surface Mount Option Available.

The ISD202 offers two channels per unit.

All electrical parameters are 100% tested by manufacturing. Specifications are guaranteed to a cumulative 0.65% AQL.

## Absolute Maximum Ratings (Ta=25°C)

Storage Temperature:	-55°C to +150°C
Operating Temperature:	-55°C to +100°C
Lead Soldering:	260°C for 10s, 1.6mm from case
Input-to-Output Isolation Voltage:	±5000Vdc ( <a href="#">note 1</a> )

## Input Diode

Forward DC Current:	60mA
Reverse DC Voltage:	3V
Peak Forward Current:	1A (PW.=100µs, duty ratio 0.001)
Power Dissipation:	100mW
Derate Linearly:	1.33mW/°C above 25°C

## Output Transistor

Collector-Emitter Voltage:	30V
Emitter-Collector Voltage:	7V
Power Dissipation:	150mW
Derate Linearly:	2.00mW/°C above 25°C

## Package

Total Power Dissipation:	400mW
Derate Linearly:	5.33mW/°C above 25°C

## Electro-optical Characteristics (Ta=25°C)

INPUT	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> =20mA		1.2	1.5	V
		I <sub>F</sub> =1mA		1	1.2	
I <sub>R</sub>	Reverse Current	V <sub>R</sub> =3V			10	µA
<b>OUTPUT</b>						
H <sub>FE</sub>		I <sub>C</sub> =100µA, V <sub>CE</sub> =5V	100	200		
BV <sub>CEO</sub>	Collector-Emitter Voltage	I <sub>C</sub> =1mA	30			V
BV <sub>ECO</sub>	Emitter-Collector Voltage	I <sub>E</sub> =0.1mA	7			V
I <sub>CEO</sub>	Collector-Emitter Dark Current	V <sub>CE</sub> =10V			50	nA
<b>COUPLED</b>	<b>PARAMETER</b>	<b>CONDITIONS</b>	<b>MIN</b>	<b>TYP</b>	<b>MAX</b>	<b>UNIT</b>
CTR	DC Current Transfer Ratio	I <sub>F</sub> =10mA, V <sub>CE</sub> =10V	125		250	%
		I <sub>F</sub> =1mA, V <sub>CE</sub> =10V	30	50		%
V <sub>CE(SAT)</sub>	Collector-Emitter Saturation Voltage	I <sub>F</sub> =10mA, I <sub>C</sub> =2.0mA		0.2	0.4	V
C <sub>F</sub>	Floating Capacitance	V=0, f=1MHz		0.6	1	pF
	Input-Output Isolation Resistance	V <sub>IO</sub> =500V (note 1)	5E11			ohm

## Notes

1. Measured with input leads shorted together and output leads shorted together.

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